

All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics									
Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit			
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				500	μA		
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$	1.4	1.7	2.1	V		
V CE(sat)	Conector Ennitier saturation voltage	$I_{\rm C} = 200 {\rm A}$	$T_{j} = 125^{\circ}C$		2.0		v		
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 8mA$		5.0	5.8	6.5	V		
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA		

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$ f = 1MHz			14		nF
C _{rss}	Reverse Transfer Capacitance				0.6		III.
Q _G	Gate charge	V_{GE} =±15V, I_C V_{CE} =600V	$V_{GE}=\pm 15V, I_{C}=200A$ $V_{CE}=600V$		1.9		μC
T _{d(on)}	Turn-on Delay Time	Inductive Swit	tching (25°C)		250		
Tr	Rise Time	$V_{GE} = \pm 15V$			90		
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 600 V$ $I_{C} = 200 A$	$V_{Bus} = 600V$ $L_c = 200A$		550		ns
T _f	Fall Time	$R_G = 3.6\Omega$			130		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_C = 200A$ $R_G = 3.6\Omega$			300		ns
Tr	Rise Time				100		
T _{d(off)}	Turn-off Delay Time				650		
T_{f}	Fall Time				180		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125^{\circ}C$		15		mI
E _{off}	Turn off Energy	$I_{C} = 200A$ $R_{G} = 3.6\Omega$	$T_j = 125^{\circ}C$		35		mJ
I _{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 900V$ $t_p \le 10\mu s$; $T_i = 125^{\circ}C$			800		А

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I _{RRM}	Maximum Reverse Leakage Current	V _R =1200V	$T_i = 25^{\circ}C$ $T_i = 125^{\circ}C$			750	μΑ
I _F	DC Forward Current		$T_1 = 123 \text{ C}$ Tc = 80°C		200	1000	А
V _F	Diode Forward Voltage	$I_{\rm F} = 200 {\rm A}$	$T_i = 25^{\circ}C$		1.6	2.1	V
▼ F		$V_{GE} = 0V$	$T_{i} = 125^{\circ}C$		1.6		v
+	Reverse Recovery Time		$T_j = 25^{\circ}C$		170		nc
t _{rr}	Reverse Recovery Time		$T_{j} = 125^{\circ}C$		280		ns
0	Deverse Decevery Charge	$I_{\rm F} = 200 \text{A}$ $V_{\rm R} = 600 \text{V}$	$T_j = 25^{\circ}C$		22		чС
Q _{rr}	Reverse Recovery Charge	$di/dt = 3500 \text{A}/\mu\text{s}$	$T_{j} = 125^{\circ}C$		40		μC
Err	Reverse Recovery Energy	Ī	$T_j = 25^{\circ}C$		9		mJ
	Reverse Recovery Energy		$T_{j} = 125^{\circ}C$		16		1115

APTGT200A120D3G-Rev 2 October 2012

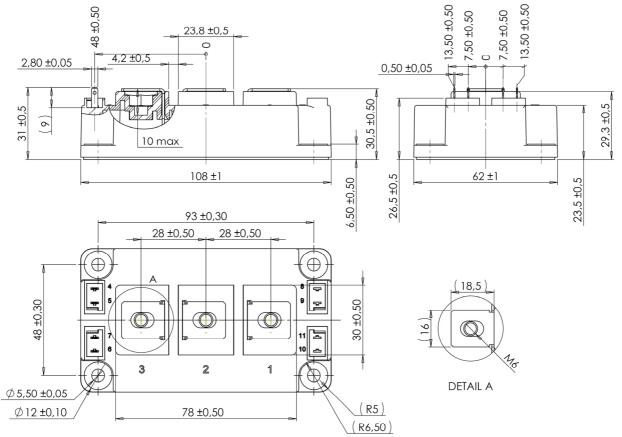


APTGT200A120D3G

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R _{thJC}	Junction to Case Thermal Resistance		IGBT			0.12	°C/W
R _{th} JC			Diode			0.20	C/ W
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range		-40		150	°C	
T _{STG}	Storage Temperature Range		-40		125		
T _C	Operating Case Temperature			-40			125
Torque	Mounting torque	For terminals	M6	3		5	N.m
		To Heatsink	M6	3		5	19.111
Wt	Package Weight				350	g	

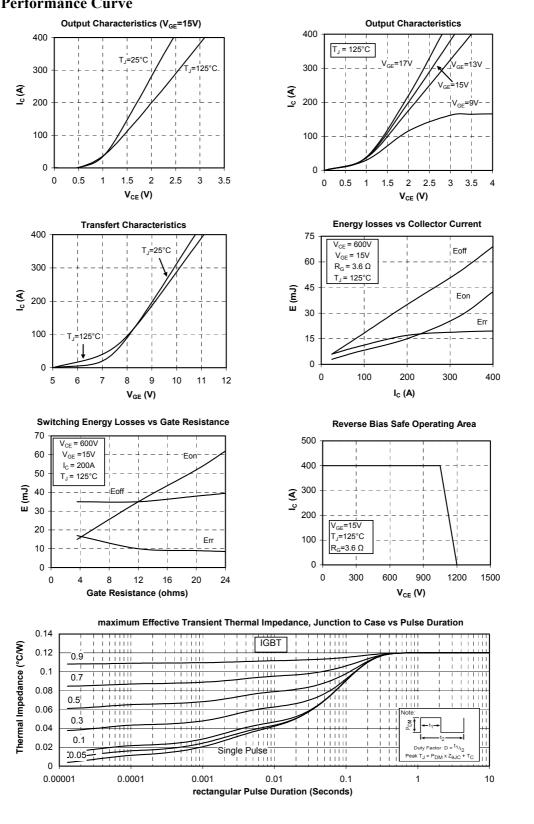
D3 Package outline (dimensions in mm)



3 - 6



Typical Performance Curve

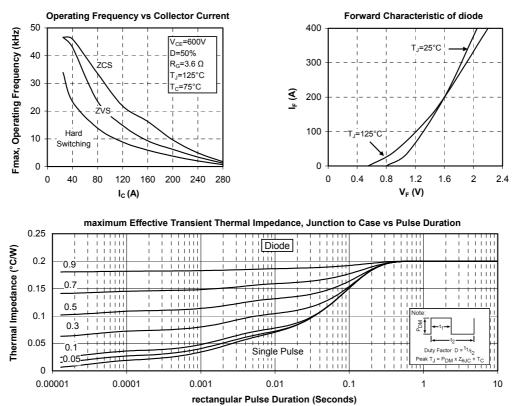


APTGT200A120D3G-Rev 2 October 2012

4 - 6



APTGT200A120D3G



 $APTGT200A120D3G-Rev\ 2 \ October\ 2012$

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5 - 6



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6 - 6